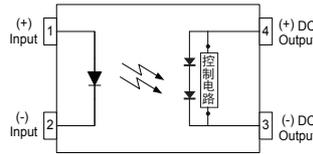
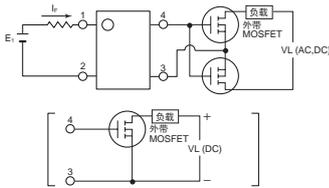




Parameter	Symbol	Rating	Units
Short circuit current	I _{sc}	8	uA
Drop-out voltage	V _{oc}	8	V
Turn-On Time	T _{on}	0.23	ms
I/O Isolation Voltage	V _{io}	2500	V _{rms}



1. LED Anode
2. LED Cathode
3. Cathode
4. Anode

(Unit: mm)



SOP-4

Function

1. High-speed switching

Since release time is 0.1 ms, the MOSFET or other load can be turned off quickly in urgent situations.

2. Space saving

With a built-in control circuit, an external resistor is not needed. This contributes to making substrates more compact.

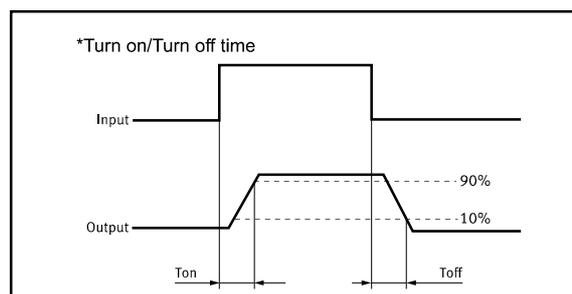
Applications

MOSFET driver

Power supply (V_{cc}) for electronic circuits

TPYES

Category	Output Rating		Package	Part No.	Packing Quantity
	Drop-out voltage (Typ.)	Short circuit current (Typ.)			
Driver	8V	8uA	SOP-4	GAQV1122S	2000pcs /reel



Absolute Maximum Ratings (Ta = 25°C)

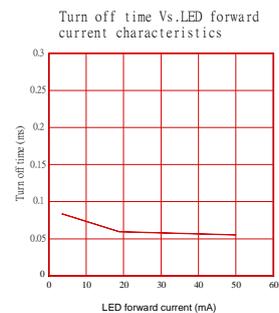
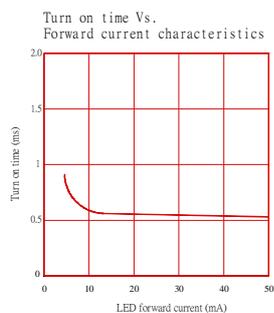
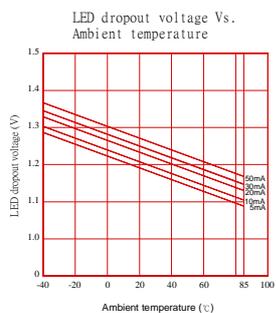
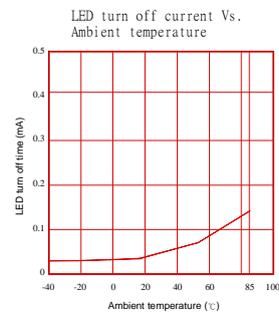
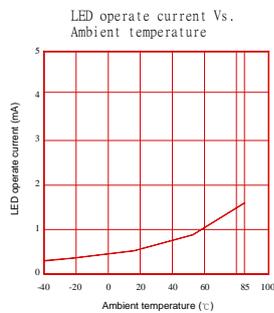
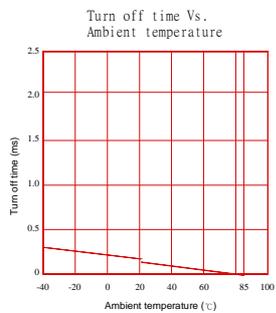
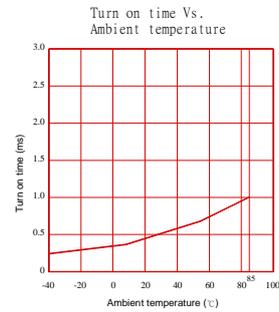
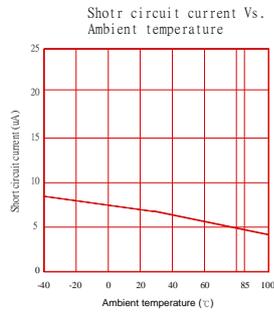
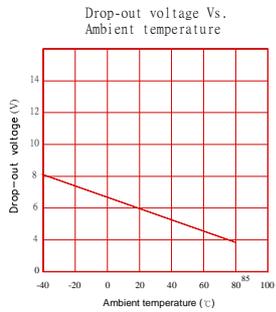
Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	1000	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
I/O Isolation Voltage		V _{I/O}	2500	V _{rms}	RH=60%, 1min
Operating Temperature		T _{Opr}	-40 to +85	°C	
Storage Temperature		T _{Stg}	-40 to +100	°C	

Electrical Characteristics (Ta = 25°C)

Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F		1.2	1.4	mA	I _F =10mA
	Operation LED Current	I _{F On}		0.5	3.0	mA	V _{oc} =5V
	Recovery LED Current	I _{F Off}		0.35	0.6	mA	V _{oc} =1V
Output	Drop-out Voltage	V _{cc}	6	8		V	I _F =10mA
	Short Circuit Current	I _{sc}	3	8		uA	I _F =10mA
Transmis sion	Turn-On Time	T _{On}		0.23		ms	I _F =10mA
	Turn-Off Time	T _{of}		0.03		ms	C _L =1000pF
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8	1.5	pF	f=1MHz

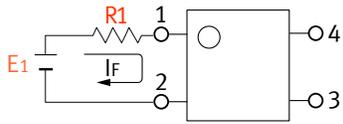
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): I_F ≥10mA and ≤30mA

Engineering Data



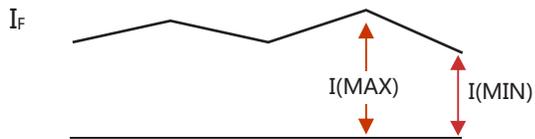
Using Methods

Examples of resistance value to control LED forward current ($I_F=20\text{mA}$)



E1	R1 (Approx)
3.3V	100 Ω
5.0V	180 Ω
12V	500 Ω
24V	1.1K Ω

LED forward current must be more than 10mA , at $I(\text{MIN})$,and less than 30mA , at $I(\text{MAX})$.



Recommended Operating Conditions

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

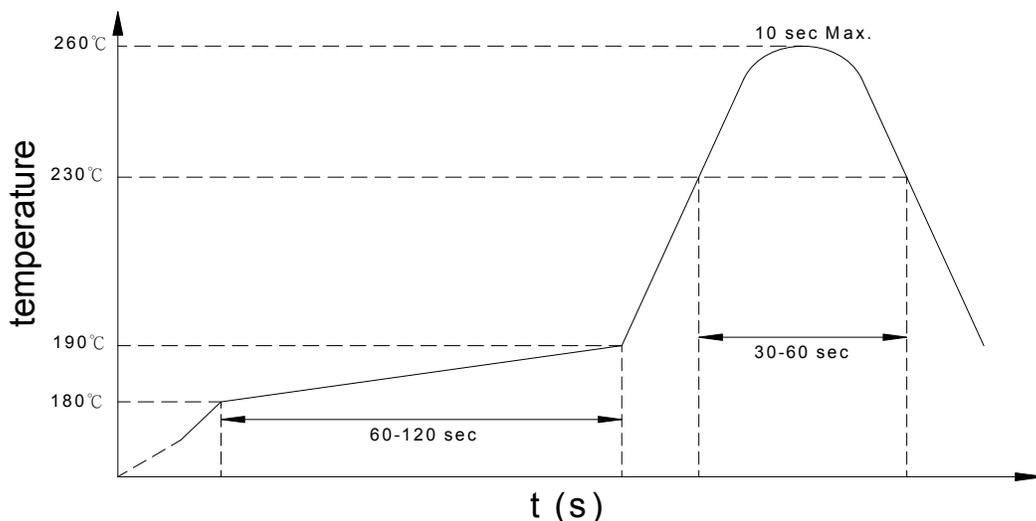
Characteristic	Symbol	Min	Typ.	Max	Unit
Forward current	I_F	10	20	30	mA

Recommended Soldering Conditions

(a) Infrared reflow soldering :

- Peak reflow soldering : 260°C or below (package surface temperature)
- Time of peak reflow temperature : 10 sec
- Time of temperature higher than 230°C : 30-60 sec
- Time to preheat temperature from 180~190°C : 60-120 sec
- Time(s) of reflow : Two
- Flux : Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



(b) Wave soldering :

- Temperature : 260°C or below (molten solder temperature)
- Time : 10 seconds or less
- Preheating conditions : 120°C or below (package surface temperature)
- Time(s) of reflow : One
- Flux : Rosin flux containing small amount of chlorine (The flux with a maximum chlorine content of 0.2 Wt% is recommended.)

(c) Cautions :

- Fluxes : Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.
- Avoid shorting between portion of frame and leads.